



Certificate

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PATENT

of Correction

Inventors: Pan et al.

Patent No.: 7,041,548 B1

Issued: May 9, 2006

For: METHODS OF FORMING A GATE STACK THAT IS VOID OF SILICON CLUSTERS WITHIN A METALLIC SILICIDE FILM THEREOF

Attorney Docket No.: 2269-2915.3US

CERTIFICATE OF MAILING

I hereby certify that this correspondence along with any attachments referred to or identified as being attached or enclosed is being deposited with the United States Postal Service as First Class Mail on the date of deposit shown below with sufficient postage and in an envelope addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22b/3-1450.

July 10, 2007

Date

Joseph A Walkowski Name (Type/Print)

LETTER MAKING ERRORS OF RECORD

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

Please make the following errors of record in the file history of the above-referenced Letters Patent:

COLUMN 1, LINE 28, change "("VSLI")" to --("VLSI")--

change "("USLI")" to --("ULSI")--COLUMN 1, LINE 29,

change "such chemical" to --such as chemical--COLUMN 1, LINE 63,

COLUMN 3, LINE 45, change "forming the" to --form the--

change "clusters 116" to --clusters 116 (as shown in COLUMN 5, LINE 54,

FIG. 10)--

U.S. Patent 7,041,548 B1

Respectfully submitted,

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